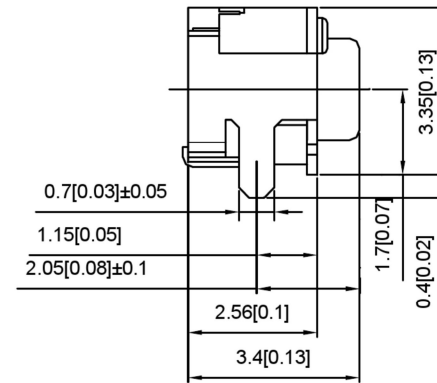
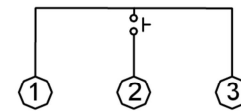
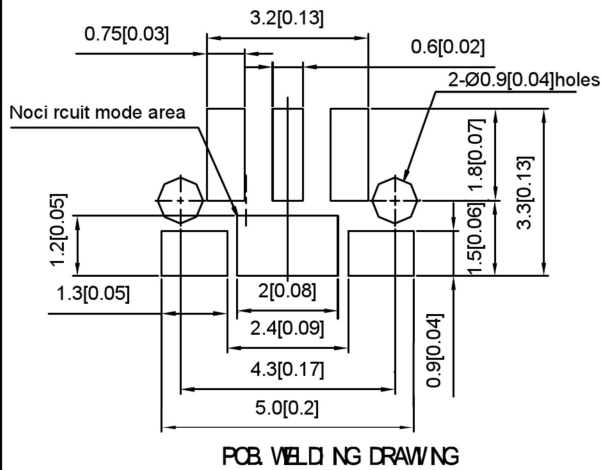


SPECIFICATION

Contact Rating: 50mA, 12V DC
 Contact Resistance: 100mΩ max
 Insulation Resistance: 100mΩ min. 500V DC
 Dielectric Strength: 250V AC/1minute
 Travel: 0.20mm
 Operating Temp: -30°C~+85°C
 Storage Temp: -30°C~+80°C



PAPT NO	TS-1133-X-B
Operating Force	A:100gf B:160gf C:260gf
Keystake	A:PA46 B:Silica gel



CIRCUIT DIAGRAM

ITEM	PAPT NAMF	TER,NO	QTY	MATERIAL	FINISHING	REMARK
⑤	Terminal	—	3	Brass (0.30t)	Plating silvering	—
④	Contact	—	1	F.ag/Sus	Natural	—
③	Base	—	1	Pa46		—
②	Cover	—	1	Spcc	Plating Nickel	—
①	Keystake	—	1	Silica gel		—

ANGLAR	±5°		DSND		SCALE: N/A	MODEL TYPE: TACT SWITCH
L ≤ 4	±0.2		DWN		VIEW:	PART NO.: TS-1133-X-B
4 < L ≤ 16	±0.3		CHKD		UNIT: mm/in	DWG NO.:
16 < L ≤ 63	±0.4		APPD		SIZE: A4	
L > 63	±0.5					
UNSPECIFIED TOLERANCES			KE SI DA ELECTRONIC TECHNOLOGY CO., LTD			WEIGHT
DATE	REVISED	APPROVED				SHEET
						1/1
						REVISI
						A0